

MUR120-MUR190

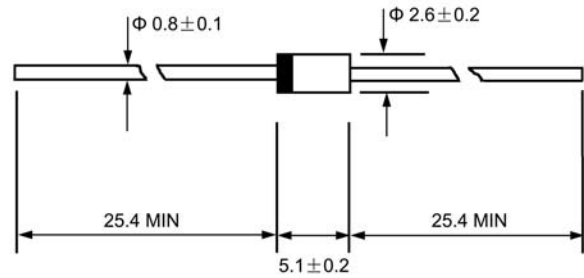
Super Fast Rectifiers

VOLTAGE RANGE: 200 --- 900 V

CURRENT: 1.0 A



DO - 41



Dimensions in millimeters

Features

- ◇ Low cost
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

Mechanical Data

- ◇ Case: JEDEC DO--41, molded plastic
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.012 ounces, 0.34 grams
- ◇ Mounting position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

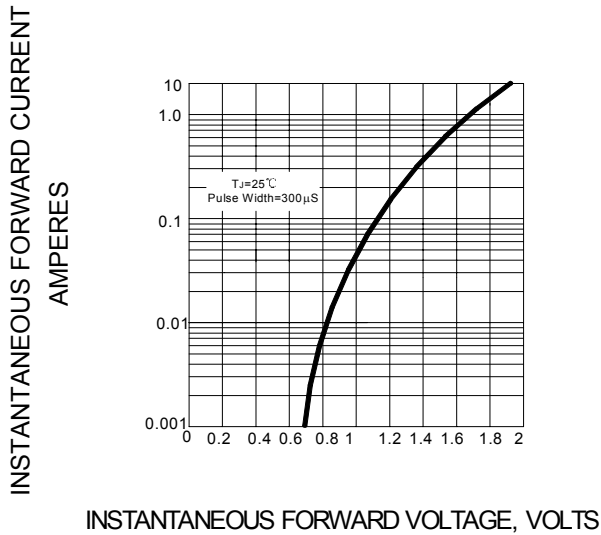
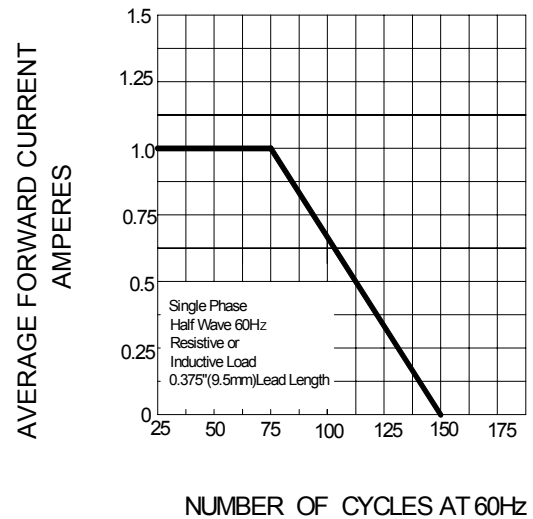
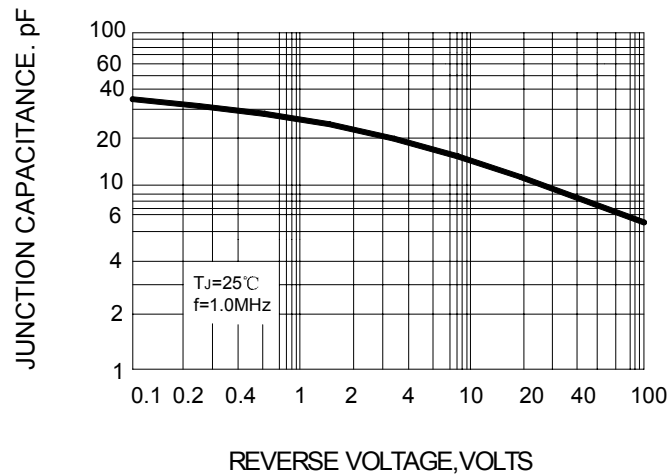
| | | MUR 120 | MUR 130 | MUR 140 | MUR 150 | MUR 160 | MUR 170 | MUR 180 | MUR 190 | UNITS |
|---|-----------------|------------------|------------|------------|------------|------------|-------------|------------|------------|--------------|
| Maximum recurrent peak reverse voltage | V_{RRM} | 200 | 300 | 400 | 500 | 600 | 700 | 800 | 900 | V |
| Maximum RMS voltage | V_{RMS} | 140 | 210 | 280 | 350 | 420 | 490 | 560 | 630 | V |
| Maximum DC blocking voltage | V_{DC} | 200 | 300 | 400 | 500 | 600 | 700 | 800 | 900 | V |
| Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ C$ | $I_{F(AV)}$ | 1.0 | | | | | | | | A |
| Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ C$ | I_{FSM} | 35.0 | | | | | | | | A |
| Maximum instantaneous forward voltage @ 1.0A | V_F | 0.875 | 1.25 | | | | 1.7 | | | V |
| Maximum reverse current @ $T_A=25^\circ C$ at rated DC blocking voltage @ $T_A=100^\circ C$ | I_R | 2.0 50 | 5.0 150 | | | | 10.0 100 | | | μA |
| Maximum reverse recovery time (Note1) | t_{rr} | 25 | 50 | | | | 75 | | | ns |
| Typical junction capacitance (Note2) | C_J | 22 | | | | 15 | | | | pF |
| Typical thermal resistance (Note3) | $R_{\theta JA}$ | 50 | | | | 60 | | | | $^\circ C/W$ |
| Operating junction temperature range | T_J | - 55 ----- + 150 | | | | | | | | $^\circ C$ |
| Storage temperature range | T_{STG} | - 55 ----- + 150 | | | | | | | | $^\circ C$ |

NOTE: 1. Measured with $I_F=0.5A$, $I_R=1A$, $I_{rr}=0.25A$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

Ratings AND Characteristic Curves

FIG.1 – TYPICAL FORWARD CHARACTERISTICS

FIG.2 – FORWARD DRATING CURVE

FIG.3 – TYPICAL JUNCTION CAPACITANCE


Ratings AND Characteristic Curves

FIG.4 – TYPICAL REVERSE CHARACTERISTICS

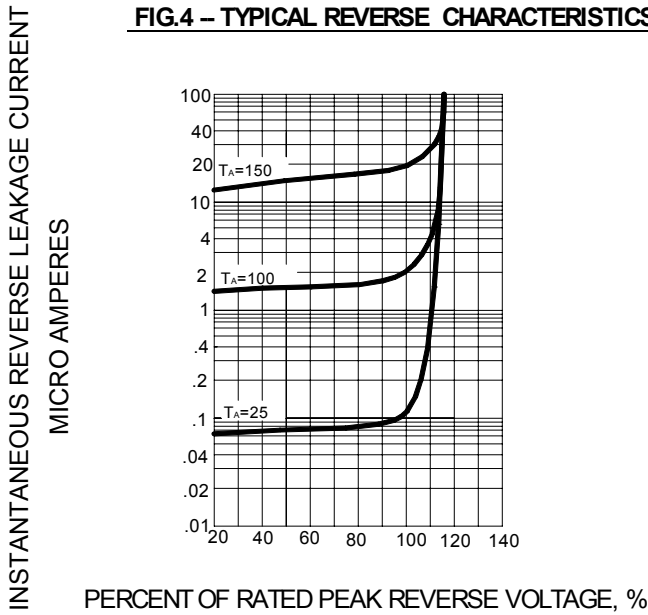


FIG.5 – PEAK FORWARD SURGE CURRENT

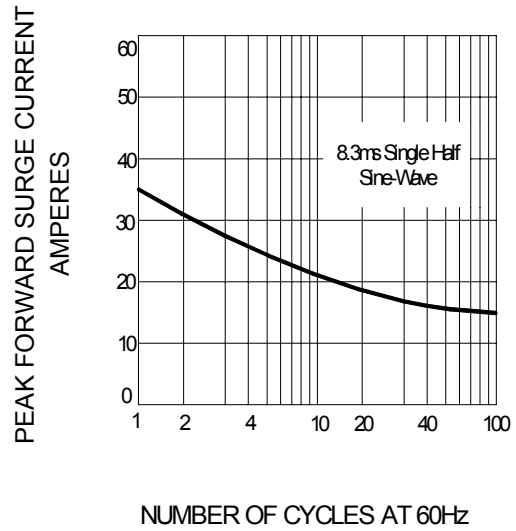
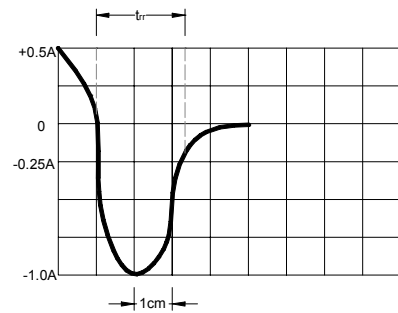
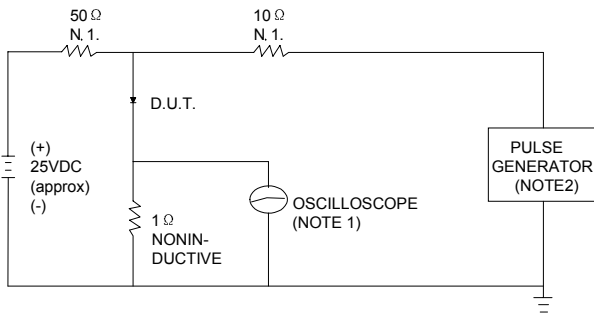


FIG.6 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. RISE TIME = 7ns MAX INPUT IMPEDANCE = 1MΩ .22pF.
 2. RISE TIME = 10ns MAX SOURCE IMPEDANCE = 50Ω.

SET TIME BASE FOR 10/20 ns/cm